NSN 5961-01-150-4605

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View Online at https://aerobasegroup.com/nsn/5961-01-150-4605

Inclosure Material:

Metal

Overall Length:

1.573 inches

Terminal Length:

Between 0.312 inches and 0.500 inches

Overall Height:

Between 0.270 inches and 0.380 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal and unthreaded hole

Features Provided:

Hermetically sealed case and quality assurance level txv

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 60.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

10.00 amperes source cutoff current

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

1 case and 2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/379 government specification

Shelf Life:

NI/o

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Demilitarization:

No

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